# Quantum critical scaling in graphene

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# Graphene

- Single-atom thick layer of graphite
  - -Theory: Wallace 47, Semenoff 84
  - Exp't: Novoselov et al 2004
     Zhang et al 2005
- Model:
  - Coulomb-interacting fermions on honeycomb lattice Lattice spacing: a = 0.142nm



– Low momenta: "relativistic" Dirac fermions  $p << \Lambda \sim \hbar/a$ 

$$H = \sum_{\mathbf{p},i} \Psi_i^{\dagger}(\mathbf{p}) [v\mathbf{p} \cdot \boldsymbol{\sigma} - \mu] \Psi_i(\mathbf{p}) + \frac{1}{2} \int d^2 \mathbf{r} d^2 \mathbf{r}' n(\mathbf{r}) n(\mathbf{r}') \frac{e^2}{\varepsilon |\mathbf{r} - \mathbf{r}'|}$$
  
Velocity  $v \approx 10^6 m/s$  dielectric

Novoselov et al Nature 2005

• Dimensionless Coulomb strength: 
$$\lambda = \frac{e^2}{4\epsilon v\hbar} \cong \frac{0.55}{\epsilon}$$
 Not small!

Breaks relativistic symmetry



Wilsonian renormalization group (RG)

TL

b

See also Gonzalez Nucl. Phys. B 94, Khveshchenko PRB 06, Son PRB 07, Herbut et al PRL 08, ...

Progressively trace over states in a thin high-p shell

 $\Lambda/b$ 

• RG equations RG near quantum critical point: Millis 93

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Low-T:

$$\lambda(b) = \frac{\pi}{1 + \lambda \ln b} \qquad T(b) = \frac{Tb}{1 + \lambda \ln b}$$

$$h \to \infty \quad \sum_{h \to 0} \lambda(h) \to 0 \quad T(h) \text{ graves}$$

$$b \rightarrow \infty \qquad \lambda(b) \rightarrow 0, \quad T(b) \text{ grows}$$

Scaling equations for observables:

e.g., density: 
$$n(\mu,T,\lambda) = b^{-2}n(\mu(b),T(b),\lambda(b))$$
  
What we want In renormalized system

Renormalized theory has *small coupling* and *high temperature* 

 $k_{y}$ 

 $k_{x}$ 

• We find: Logarithmic corrections to observables

Electronic compressibility 
$$\kappa^{-1} = \frac{\partial \mu}{\partial n}$$
  
• High-T regime  $T >> \mu$ :  $\kappa^{-1} = \frac{\pi v^2}{4T \ln 2} \left(1 + \lambda \ln \frac{T_0}{T}\right)^2$   
Any T for intrinsic graphene...  
Free Dirac  
Log correction depends on Temperature  
• Finite density, low T: RG condition  
 $\kappa^{-1} \approx v \sqrt{\frac{\pi}{4|n|}} \left(1 + \frac{\lambda}{2} \ln \frac{n_0}{|n|}\right)^{\kappa}$   
See Also: Hwang et al PRL 07

• Scales appearing in Log factors: Interaction effects are important!  $T_0 \approx 8 \times 10^4 K$  $n_0 \approx 4 \times 10^{15} cm^{-2}$ 

• Logarithmic correction: determined by dominant relevant perturbation

#### Recent compressibility data

J. Martin, N. Akerman, G. Ulbricht, T. Lohmann, J. H. Smet, K. von Klitzing, A. Yacoby, Nat. Phys. (2007)

Low T limit:



- Interactions necessary to understand data
- More data needed to observe ln(n) dependence

Next: specific heat

# Specific heat

•  $|\mu| >> T$  : electron  $(\mu > 0)$  or hole  $(\mu < 0)$  Fermi surface :

Fermi Liquid regime 
$$C \cong \gamma T$$
  
 $\gamma = \frac{N\pi |\mu|}{6v^2} \frac{1}{[1 + \lambda \ln(v\Lambda/|\mu|)]^2}$   
Free Dirac Log correction  
• Dirac liquid:  $\mu \ll T$   $C \cong \frac{9N\zeta(3)}{2\pi v^2} \frac{T^2}{[1 + \lambda \ln(v\Lambda/T)]^2}$  Log correction  
Perturbation theory\*:  $C \approx \frac{9N\zeta(3)}{2\pi v^2} T^2 [1 - 2\lambda \ln(v\Lambda/T)]$  Unphysical at low T  
\*Vafek PRL 07  
RG prediction: True low-T behavior  $C \propto \frac{T^2}{[\ln(v\Lambda/T)]^2}$ 

Next: magnetic field



• Dashed line: Crossover between two regimes

Magnetic susceptibility  $\chi(T,\lambda,B)$ 

# Finite-temperature, B=0

$$\chi(T,\lambda,0) \approx -\frac{e^2 v^2}{6\pi c^2} \frac{1}{T} \times \left(1 + \lambda \ln \frac{v\Lambda}{T}\right)^2$$
  
Free Dirac fermions\* Logarithmic correction

Enhanced Landau diamagnetism!

## Finite-field, T=0

$$\chi(0,\lambda,B) \cong -\frac{3\varsigma(3)}{16\pi^2} \left(\frac{2e}{c}\right)^{3/2} \frac{v}{\sqrt{B}} \times \left(1 + \frac{1}{2}\lambda \ln \frac{B_0}{B}\right)$$
  
Free Dirac\* Leading-log correction

Interactions increase singular diamagnetism!

\*Nersesyan & Vachnadze JLTP 1989 Sharapov et al PRB 2004 Ghosal et al PRB 2007

Next: Magnetization

### Magnetization vs. B

$$M(0,\lambda,B) \cong -\frac{3\varsigma(3)}{8\pi^2} \left(\frac{2e}{c}\right)^{3/2} v \sqrt{B} \times \left(1 + \frac{1}{2}\lambda \ln \frac{B_0}{B}\right)$$



**Next: Conductivity** 

## Conductivity of clean graphene

• Scaling of  $\sigma(\mathbf{q},\omega)$ : Constrained by a Ward identity Gross, Les Houches, 1975

$$\sigma(\omega, T, \lambda) = \sigma(\omega(b), T(b), \lambda(b))$$

• Perturbation theory in renormalized coupling:

$$\sigma(\omega,T,\lambda) = \sigma_0(\omega,T) + \lambda(b)\sigma_1(\omega,T)$$

• Low- $T \ll \omega$  regime: Interaction effects vanish



#### Concluding remarks

Graphene: Dirac fermions with Coulomb interaction (Marginal)

Interaction effects: Log corrections to free case (Dirac fermions)

Renormalization group: Scaling equations for various quantities

Specific heat, compressibility, diamagnetic susceptibility, dielectric function, ...

Velocity renormalization: 
$$v \rightarrow v (1 + \lambda \ln[v\Lambda/T])$$
  
 $v \rightarrow v (1 + \frac{1}{2}\lambda \ln[n_0/n])$ 

Observing interaction effects:

Wide T or n regime, or combined n and T analysis